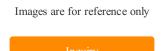


IXBH40N160

Trans IGBT Chip N-CH 1600V 33A 350mW 3-Pin(3+Tab) TO-247AD

Manufacturer:	Littelfuse Inc
Package/Case:	TO-247
Product Type:	Thyristors
Lifecycle:	NRND

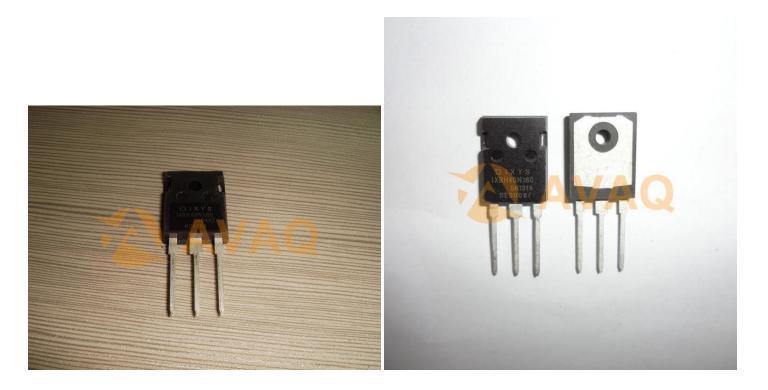




General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this "free" intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features	Application
High blocking voltage	Radar transmitter power supplies
High power density	Radar pulse modulators
High current handling capability	Capacitor discharge circuits
Low conduction losses	
MOS gate turn on for drive simplicity	High voltage power supplies
International standard and proprietary ISOPLUSTM packages	AC switches
Benefits:	HV circuit breakers
Eliminates multiple series-parallel lower voltage, lower current rateddevices	Pulser circuits
Simpler system design	High voltage test equipment
Improved reliability	ngn voluge test equipment
Reduced component count	Laser & X-ray generators
Reduced system cost	



Recommended For You

IXGH48N60C3D1	IXYX100N120C3	IXGH30N60B2D1
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
TO-247	PLUS247	TO-247
IXYN30N170CV1	IXBH16N170	IXGH60N60C2
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
Ν	TO-247	TO-247
IXGH48N60A3	IXGN320N60A3	IXGH60N60C3
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
TO-247	MODULE	TO-247
IXGP20N120A3	IXYR50N120C3D1	IXYH50N65C3D1
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
TO-220	ISOPLUS247	TO-247
IXGP8N100	IXTQ460P2	IXGR48N60C3D1
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc

TO-3P

TO-220

TO-247